NSN 5961-01-213-6467

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-213-6467 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.050 inches **Overall Diameter:** 0.055 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 8.0 working peak reverse voltage **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 100.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 0.25 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Plated leads gold **Precious Material:** Gold **Test Data Document:** 82577-925196 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**